



CERTIFICATE

No. Z2 120422 0002 Rev. 01

Holder of Certificate:

Qn-SOLAR PV LIMITED

Unit 2 of LG 1, Mirror Tower, 61 Mody Road 999077 Tsim Sha Tsui, Kowloon HONG KONG

Certification Mark:



Product:

Crystalline Silicon Terrestrial Photovoltaic (PV) Modules Mono-crystalline Silicon Photovoltaic (PV) Modules

The product was tested on a voluntary basis and complies with the essential requirements. The certification mark shown above can be affixed on the product. It is not permitted to alter the certification mark in any way. In addition, the certification holder must not transfer the certificate to third parties. This certificate is valid until the listed date, unless it is cancelled earlier. All applicable requirements of the testing and certification regulations of TÜV SÜD Group have to be complied. For details see: www.tuvsud.com/ps-cert

Test report no.:

882162303102

Valid until:

2028-02-26

Date,

2023-06-26

(Xinlian LUO)



CERTIFICATE

No. Z2 120422 0002 Rev. 01

Model(s):

With $\frac{1}{2}$ cut of 210 mono c-Si cell (132pcs): QNM210-HSxxx-66 (XXX=650-670, in step of 5) With $\frac{1}{2}$ cut of 210 mono c-Si cell (120pcs): QNM210-HSxxx-60 (XXX=590-610, in step of 5) With $\frac{1}{2}$ cut of 210 mono c-Si cell (110pcs): QNM210-HSxxx-55 (XXX=540-560, in step of 5) With ¹/₃ cut of 210 mono c-Si cell (150pcs): QNM210-HSxxx-50 (XXX=490-510, in step of 5) With $\frac{1}{2}$ cut of 182 mono c-Si cell (144pcs): QNM182-HSxxx-72 (xxx=525-555, in step of 5) With $\frac{1}{2}$ cut of 182 mono c-Si cell (132pcs): QNM182-HSxxx-66 (xxx=480-500, in step of 5) With ¹/₂ cut of 182 mono c-Si cell (120pcs): QNM182-HSxxx-60(xxx=440-460, in step of 5) With 1/2 cut of 182 mono c-Si cell (108pcs): QNM182-HSxxx-54 (xxx=395-415, in step of 5) With $\frac{1}{2}$ cut of 210 mono c-Si cell (132pcs): QNN210-HSxxx-66 (xxx=670-695, in step of 5) With $\frac{1}{2}$ cut of 210 mono c-Si cell (120pcs): QNN210-HSxxx-60 (xxx=610-630, in step of 5) With $\frac{1}{2}$ cut of 210 mono c-Si cell (110pcs): QNN210-HSxxx-55 (xxx=555-575, in step of 5) With $\frac{1}{2}$ cut of 182 mono c-Si cell (144pcs): QNN182-HSxxx-72 (xxx=555-575, in step of 5) With ¹/₂ cut of 182 mono c-Si cell (120pcs): QNN182-HSxxx-60(xxx=465-475, in step of 5) With $\frac{1}{2}$ cut of 182 mono c-Si cell (108pcs): QNN182-HSxxx-54 (xxx=415-430, in step of 5) xxx is standing for rated output power at STC

Parameters:

Safety Class: Class II Max. System Voltage: 1500 V DC Fire Safety Class: Class C according to UL790. Test Laboratory: Metrology and Testing Center of China Electronics Technology Group Corporation No.18th Research Institute (NO.6 Huake seven RD, Haitai street, Xiqing District, Tianjin,300384, China) Construction: Framed, with Junction box, Cable and Connector.

Production Facilities:
1. Jiangsu Zhongqing Photovoltaic Technology Co., Ltd.
26, North Side of Taishan Road, Xiyi High-tech Zone, Xinyi City
Production Facility Number: 119915
2. ZhongQing Intelligence Industrial (HuBei) Co.,LTD.
Shuanglian Industrial Park, Dangyang Economic Development Zone, Hu-bei Province
Production Facility Number: 120038



CERTIFICATE

No. Z2 120422 0002 Rev. 01

Tested according to:

IEC 61215-1:2016 IEC 61215-1-1:2016 IEC 61215-2:2016 IEC 61730-1:2016 IEC 61730-2:2016 EN 61215-1:2016 EN 61215-1:2016 EN 61215-2:2017 EN IEC 61730-1:2018 EN IEC 61730-2:2018 EN IEC 61730-2:2018/AC:2018-06 EN IEC 61730-2:2018/AC:2018-06